

| L Number | Hits | Search Text | DB | Time stamp |
|----------|------|--|---|---------------------|
| - | 11 | 136/\$.ccls. and (nucleation adj layer) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 12:55 |
| - | 1520 | 136/249,255,261,262.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 11:17 |
| - | 81 | 438/74.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 11:17 |
| - | 16 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (triple adj junction) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 11:25 |
| - | 225 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (semiconductor adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 11:26 |
| - | 30 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (germanium adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 11:26 |
| - | 11 | 4835116.URPN. | USPAT | 2002/05/10 12:40 |
| - | 23 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (lattice adj parameter) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:51 |
| - | 61 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:52 |
| - | 1 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (germanium adj substrate)) and ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:53 |
| - | 1 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (germanium near substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:53 |
| - | 2 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (germanium near2 substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:53 |
| - | 2 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (germanium near3 substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 13:54 |

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|---|------|---|---|---------------------|
| - | 24 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (semiconductor adj substrate) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:00 |
| - | 5 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (semiconductor adj substrate)) and germanium | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:00 |
| - | 12 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and germanium | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:13 |
| - | 7 | ((136/249,255,261,262.ccls. or 438/74.ccls.) and (junction near depth)) and (two adj step) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:51 |
| - | 4 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (AM0 near2 efficiency) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:21 |
| - | 6 | 136/\$.ccls. and (AM0 near2 efficiency) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:21 |
| - | 10 | (136/249,255,261,262.ccls. or 438/74.ccls.) and ((solid adj state) near2 diffusion) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 14:53 |
| - | 7 | 136/\$.ccls. and mocvd and movpe | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 15:17 |
| - | 1547 | 136/249,255,261,262.ccls. or 438/74.ccls. | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 16:37 |
| - | 1 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (oxide adj desorption) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 16:37 |
| - | 0 | (136/249,255,261,262.ccls. or 438/74.ccls.) and (oxygen adj desorption) | USPAT; US-PGPUB; EPO; JPO; DERWENT | 2002/05/10 16:37 |